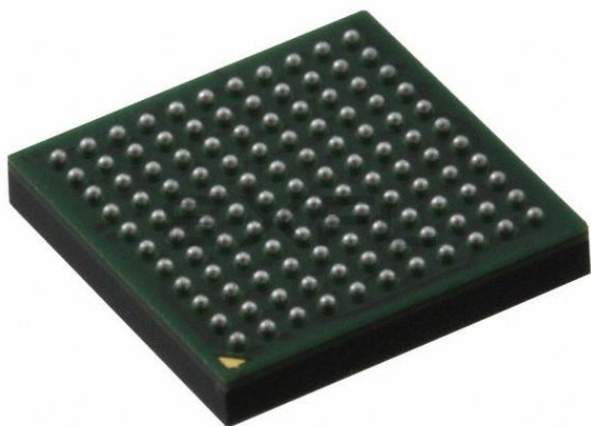




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Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	120MHz
Connectivity	I ² C, IrDA, SPI, UART/USART, USB, USB OTG
Peripherals	DMA, I ² S, LVD, POR, PWM, WDT
Number of I/O	70
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	48K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 36x16b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	121-XFBGA
Supplier Device Package	121-BGA (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mk22fn256vdc12

Table of Contents

1 Ratings.....	5	3.6.1 ADC electrical specifications.....	34
1.1 Thermal handling ratings.....	5	3.6.2 CMP and 6-bit DAC electrical specifications.....	38
1.2 Moisture handling ratings.....	5	3.6.3 12-bit DAC electrical characteristics.....	41
1.3 ESD handling ratings.....	5	3.6.4 Voltage reference electrical specifications.....	44
1.4 Voltage and current operating ratings.....	5	3.7 Timers.....	45
2 General.....	6	3.8 Communication interfaces.....	45
2.1 AC electrical characteristics.....	6	3.8.1 USB electrical specifications.....	46
2.2 Nonswitching electrical specifications.....	6	3.8.2 USB VREG electrical specifications.....	46
2.2.1 Voltage and current operating requirements.....	6	3.8.3 DSPI switching specifications (limited voltage range).....	47
2.2.2 LVD and POR operating requirements.....	7	3.8.4 DSPI switching specifications (full voltage range).....	49
2.2.3 Voltage and current operating behaviors.....	8	3.8.5 Inter-Integrated Circuit Interface (I2C) timing.....	50
2.2.4 Power mode transition operating behaviors.....	9	3.8.6 UART switching specifications.....	52
2.2.5 Power consumption operating behaviors.....	10	3.8.7 I2S/SAI switching specifications.....	52
2.2.6 EMC radiated emissions operating behaviors.....	17	4 Dimensions.....	58
2.2.7 Designing with radiated emissions in mind.....	18	4.1 Obtaining package dimensions.....	58
2.2.8 Capacitance attributes.....	18	5 Pinout.....	59
2.3 Switching specifications.....	18	5.1 K22F Signal Multiplexing and Pin Assignments.....	59
2.3.1 Device clock specifications.....	18	5.2 Recommended connection for unused analog and digital pins.....	64
2.3.2 General switching specifications.....	19	5.3 K22F Pinouts.....	65
2.4 Thermal specifications.....	20	6 Part identification.....	69
2.4.1 Thermal operating requirements.....	20	6.1 Description.....	69
2.4.2 Thermal attributes.....	20	6.2 Format.....	69
3 Peripheral operating requirements and behaviors.....	21	6.3 Fields.....	70
3.1 Core modules.....	21	6.4 Example.....	70
3.1.1 SWD electricals	21	6.5 121-pin XFBGA part marking.....	71
3.1.2 JTAG electricals.....	22	6.6 64-pin MAPBGA part marking.....	71
3.2 System modules.....	25	7 Terminology and guidelines.....	71
3.3 Clock modules.....	25	7.1 Definitions.....	71
3.3.1 MCG specifications.....	25	7.2 Examples.....	72
3.3.2 IRC48M specifications.....	28	7.3 Typical-value conditions.....	72
3.3.3 Oscillator electrical specifications.....	28	7.4 Relationship between ratings and operating requirements.....	73
3.3.4 32 kHz oscillator electrical characteristics.....	31	7.5 Guidelines for ratings and operating requirements.....	73
3.4 Memories and memory interfaces.....	31	8 Revision History.....	73
3.4.1 Flash electrical specifications.....	31		
3.4.2 EzPort switching specifications.....	33		
3.5 Security and integrity modules.....	34		
3.6 Analog.....	34		

1 Ratings

1.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T _{STG}	Storage temperature	−55	150	°C	1
T _{SDR}	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

1.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

1.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V _{HBM}	Electrostatic discharge voltage, human body model	−2000	+2000	V	1
V _{CDM}	Electrostatic discharge voltage, charged-device model	−500	+500	V	2
I _{LAT}	Latch-up current at ambient temperature of 105°C	−100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

1.4 Voltage and current operating ratings

Table 4. Voltage and current operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{OL}	Output low voltage — Normal drive pad except RESET_B					
	2.7 V ≤ V _{DD} ≤ 3.6 V, I _{OL} = 5 mA	—	—	0.5	V	1
	1.71 V ≤ V _{DD} ≤ 2.7 V, I _{OL} = 2.5 mA	—	—	0.5	V	
V _{OL}	Output low voltage — High drive pad except RESET_B					
	2.7 V ≤ V _{DD} ≤ 3.6 V, I _{OL} = 20 mA	—	—	0.5	V	1
	1.71 V ≤ V _{DD} ≤ 2.7 V, I _{OL} = 10 mA	—	—	0.5	V	
V _{OL}	Output low voltage — RESET_B					
	2.7 V ≤ V _{DD} ≤ 3.6 V, I _{OL} = 3 mA	—	—	0.5	V	
	1.71 V ≤ V _{DD} ≤ 2.7 V, I _{OL} = 1.5 mA	—	—	0.5	V	
I _{OLT}	Output low current total for all ports	—	—	100	mA	
I _{IN}	Input leakage current (per pin) for full temperature range					
	All pins other than high drive port pins	—	0.002	0.5	μA	1, 2
	High drive port pins	—	0.004	0.5	μA	
I _{IN}	Input leakage current (total all pins) for full temperature range	—	—	1.0	μA	2
R _{PU}	Internal pullup resistors	20	—	50	kΩ	3
R _{PD}	Internal pulldown resistors	20	—	50	kΩ	4

1. PTB0, PTB1, PTC3, PTC4, PTD4, PTD5, PTD6, and PTD7 I/O have both high drive and normal drive capability selected by the associated PTx_PCRn[DSE] control bit. All other GPIOs are normal drive only.

2. Measured at V_{DD}=3.6V

3. Measured at V_{DD} supply voltage = V_{DD} min and V_{input} = V_{SS}

4. Measured at V_{DD} supply voltage = V_{DD} min and V_{input} = V_{DD}

2.2.4 Power mode transition operating behaviors

All specifications except t_{POR}, and VLLSx→RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 80 MHz
- Bus clock = 40 MHz
- Flash clock = 20 MHz
- MCG mode: FEI

Table 5. Power mode transition operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t _{POR}	After a POR event, amount of time from the point V _{DD} reaches 1.71 V to execution of the	—	—	300	μs	1

Table continues on the next page...

Table 5. Power mode transition operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	first instruction across the operating temperature range of the chip.					
	• VLLS0 → RUN	—	—	140	μs	
	• VLLS1 → RUN	—	—	140	μs	
	• VLLS2 → RUN	—	—	80	μs	
	• VLLS3 → RUN	—	—	80	μs	
	• LLS2 → RUN	—	—	6	μs	
	• LLS3 → RUN	—	—	6	μs	
	• VLPS → RUN	—	—	5.7	μs	
	• STOP → RUN	—	—	5.7	μs	

1. Normal boot (FTFA_OPT[LPBOOT]=1)

2.2.5 Power consumption operating behaviors

The current parameters in the table below are derived from code executing a while(1) loop from flash, unless otherwise noted.

The IDD typical values represent the statistical mean at 25°C, and the IDD maximum values for RUN, WAIT, VLPR, and VLPW represent data collected at 125°C junction temperature unless otherwise noted. The maximum values represent characterized results equivalent to the mean plus three times the standard deviation (mean + 3 sigma).

Table 6. Power consumption operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I _{DDA}	Analog supply current	—	—	See note	mA	1
I _{DD_HSRUN}	High Speed Run mode current - all peripheral clocks disabled, CoreMark benchmark code executing from flash @ 1.8V	—	25.66	26.35	mA	2, 3, 4

Table continues on the next page...

Table 6. Power consumption operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	@ 105°C	—	15.3	27.65	μA	
I _{DD_VLLS2}	Very low-leakage stop mode 2 current at 3.0 V					
	@ -40°C to 25°C	—	1.7	2.10	μA	
	@ 70°C	—	3.4	4.85	μA	
	@ 85°C	—	5.1	8.80	μA	
	@ 105°C	—	9.8	15.70	μA	
I _{DD_VLLS1}	Very low-leakage stop mode 1 current at 3.0 V					
	@ -40°C to 25°C	—	0.71	0.96	μA	
	@ 70°C	—	1.79	2.10	μA	
	@ 85°C	—	2.9	4.70	μA	
	@ 105°C	—	5.7	8.10	μA	
I _{DD_VLLS0}	Very low-leakage stop mode 0 current at 3.0 V with POR detect circuit enabled					
	@ -40°C to 25°C	—	0.40	0.56	μA	
	@ 70°C	—	1.39	1.70	μA	
	@ 85°C	—	2.5	4.25	μA	
	@ 105°C	—	5.3	7.50	μA	
I _{DD_VLLS0}	Very low-leakage stop mode 0 current at 3.0 V with POR detect circuit disabled					
	@ -40°C to 25°C	—	0.12	0.38	μA	
	@ 70°C	—	1.05	1.38	μA	
	@ 85°C	—	2.20	3.95	μA	
	@ 105°C	—	4.9	7.10	μA	
I _{DD_VBAT}	Average current with RTC and 32kHz disabled at 3.0 V					
	@ -40°C to 25°C	—	0.18	0.21	μA	
	@ 70°C	—	0.66	0.86	μA	
	@ 85°C	—	1.52	2.24	μA	
	@ 105°C	—	2.92	4.30	μA	
I _{DD_VBAT}	Average current when CPU is not accessing RTC registers					
	@ 1.8V					
	• @ -40°C to 25°C	—	0.59	0.70	μA	15
	• @ 70°C	—	1.00	1.3	μA	
	• @ 85°C	—	1.76	2.59	μA	
	• @ 105°C	—	3.00	4.42	μA	
	@ 3.0V					
	• @ -40°C to 25°C	—	0.71	0.84	μA	

Table continues on the next page...

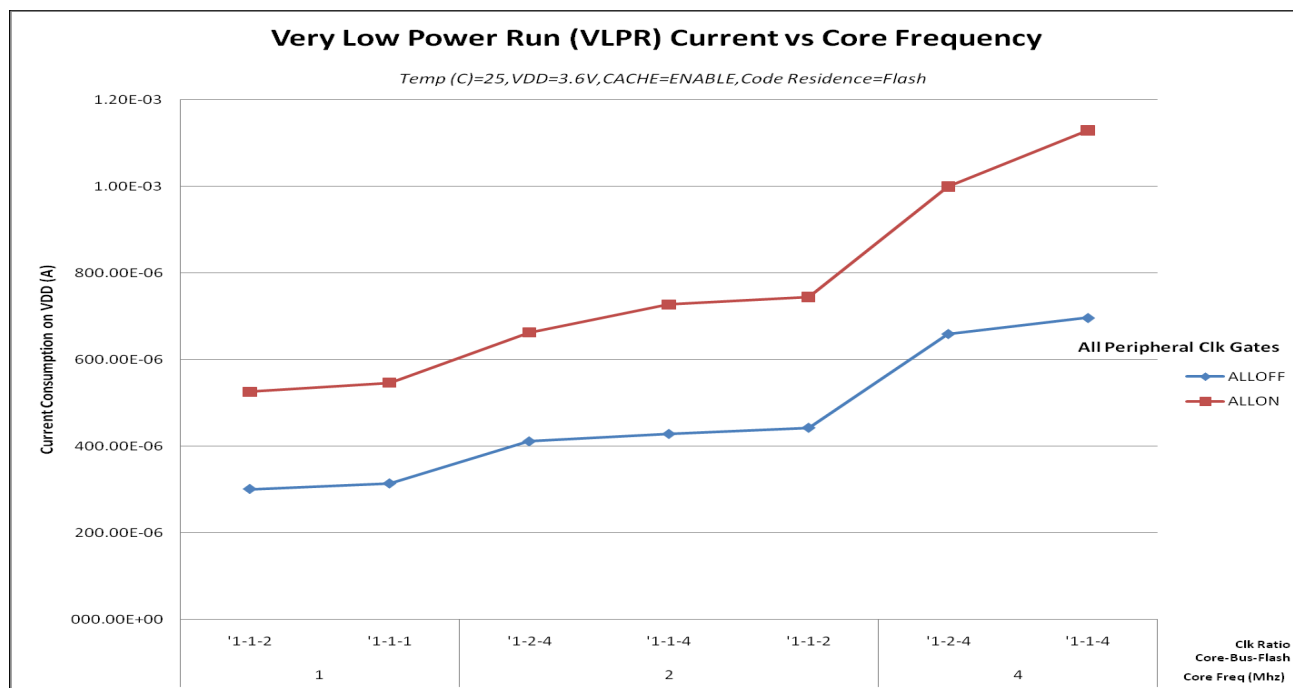


Figure 4. VLPR mode supply current vs. core frequency

2.2.6 EMC radiated emissions operating behaviors

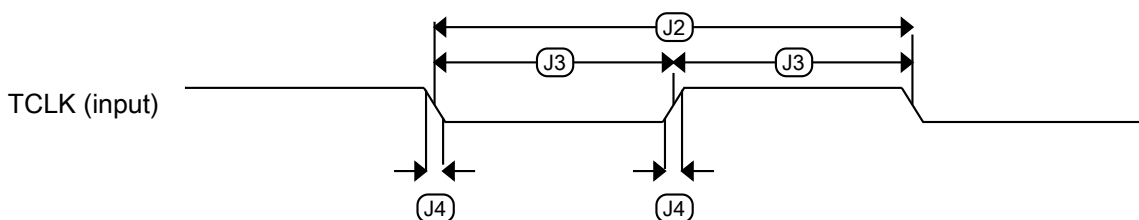
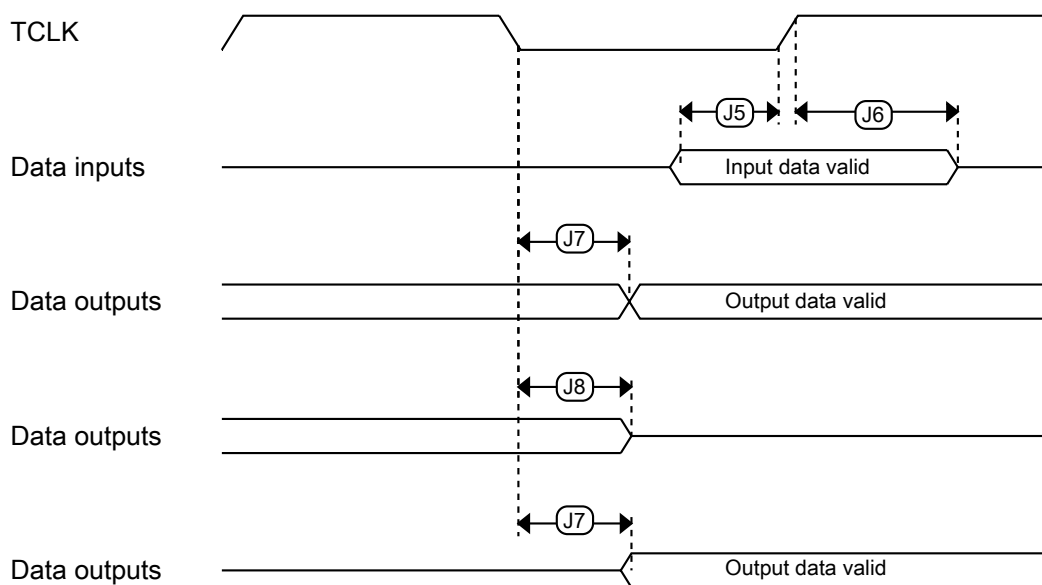
Table 8. EMC radiated emissions operating behaviors for 64 LQFP package

Parameter	Conditions	Clocks	Frequency range	Level (Typ.)	Unit	Notes
V _{EME}	Device configuration, test conditions and EM testing per standard IEC 61967-2. Supply voltages: - VREGIN (USB) = 5.0 V - VDD = 3.3 V Temp = 25°C	FSYS = 120 MHz FBUS = 60 MHz External crystal = 8 MHz	150 kHz–50 MHz	14	dBuV	1, 2, 3
			50 MHz–150 MHz	23		
			150 MHz–500 MHz	23		
			500 MHz–1000 MHz	9		
			IEC level	L		4

1. Measurements were made per IEC 61967-2 while the device was running typical application code.
2. Measurements were performed on the 64LQFP device, MK22FN512VLH12.

Table 15. JTAG full voltage range electricals (continued)

Symbol	Description	Min.	Max.	Unit
J8	TCLK low to boundary scan output high-Z	—	27	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1.4	—	ns
J11	TCLK low to TDO data valid	—	26.2	ns
J12	TCLK low to TDO high-Z	—	26.2	ns
J13	TRST assert time	100	—	ns
J14	TRST setup time (negation) to TCLK high	8	—	ns

**Figure 7. Test clock input timing****Figure 8. Boundary scan (JTAG) timing**

3.3.2 IRC48M specifications

Table 17. IRC48M specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{DD}	Supply voltage	1.71	—	3.6	V	
I_{DD48M}	Supply current	—	400	500	μA	
f_{irc48m}	Internal reference frequency	—	48	—	MHz	
$\Delta f_{irc48m_ol_hv}$	Open loop total deviation of IRC48M frequency at high voltage ($V_{DD}=1.89V-3.6V$) over $0^{\circ}C$ to $70^{\circ}C$ Regulator enable (<code>USB_CLK_RECOVER_IRC_EN[REG_EN]=1</code>)	—	± 0.2	± 0.5	$\%f_{irc48m}$	1
$\Delta f_{irc48m_ol_hv}$	Open loop total deviation of IRC48M frequency at high voltage ($V_{DD}=1.89V-3.6V$) over full temperature Regulator enable (<code>USB_CLK_RECOVER_IRC_EN[REG_EN]=1</code>)	—	± 0.4	± 1.0	$\%f_{irc48m}$	1
$\Delta f_{irc48m_ol_lv}$	Open loop total deviation of IRC48M frequency at low voltage ($V_{DD}=1.71V-1.89V$) over full temperature Regulator disable (<code>USB_CLK_RECOVER_IRC_EN[REG_EN]=0</code>) Regulator enable (<code>USB_CLK_RECOVER_IRC_EN[REG_EN]=1</code>)	—	± 0.4 ± 0.5	± 1.0 ± 1.5	$\%f_{irc48m}$	1
Δf_{irc48m_cl}	Closed loop total deviation of IRC48M frequency over voltage and temperature	—	—	± 0.1	$\%f_{host}$	2
J_{cyc_irc48m}	Period Jitter (RMS)	—	35	150	ps	
$t_{irc48mst}$	Startup time	—	2	3	μs	3

1. The maximum value represents characterized results equivalent to the mean plus or minus three times the standard deviation (mean ± 3 sigma).
2. Closed loop operation of the IRC48M is only feasible for USB device operation; it is not usable for USB host operation. It is enabled by configuring for USB Device, selecting IRC48M as USB clock source, and enabling the clock recover function (`USB_CLK_RECOVER_IRC_CTRL[CLOCK_RECOVER_EN]=1`, `USB_CLK_RECOVER_IRC_EN[IRC_EN]=1`).
3. IRC48M startup time is defined as the time between clock enablement and clock availability for system use. Enable the clock by one of the following settings:
 - `USB_CLK_RECOVER_IRC_EN[IRC_EN]=1` or
 - MCG operating in an external clocking mode and `MCG_C7[OSCSEL]=10` or `MCG_C5[PLLCLKEN0]=1`, or
 - `SIM_SOPT2[PLLFLSEL]=11`

3.3.3 Oscillator electrical specifications

3.3.3.1 Oscillator DC electrical specifications

Table 18. Oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{DD}	Supply voltage	1.71	—	3.6	V	
I_{DDOSC}	Supply current — low-power mode (HGO=0)					1
	• 32 kHz	—	500	—	nA	
	• 4 MHz	—	200	—	μ A	
	• 8 MHz (RANGE=01)	—	300	—	μ A	
	• 16 MHz	—	950	—	μ A	
	• 24 MHz	—	1.2	—	mA	
	• 32 MHz	—	1.5	—	mA	
I_{DDOSC}	Supply current — high-gain mode (HGO=1)					1
	• 32 kHz	—	25	—	μ A	
	• 4 MHz	—	400	—	μ A	
	• 8 MHz (RANGE=01)	—	500	—	μ A	
	• 16 MHz	—	2.5	—	mA	
	• 24 MHz	—	3	—	mA	
	• 32 MHz	—	4	—	mA	
C_x	EXTAL load capacitance	—	—	—		2, 3
C_y	XTAL load capacitance	—	—	—		2, 3
R_F	Feedback resistor — low-frequency, low-power mode (HGO=0)	—	—	—	M Ω	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	M Ω	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—	—	M Ω	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	—	M Ω	
R_S	Series resistor — low-frequency, low-power mode (HGO=0)	—	—	—	k Ω	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200	—	k Ω	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	—	—	k Ω	
	Series resistor — high-frequency, high-gain mode (HGO=1)	—	0	—	k Ω	
V_{pp} ⁵	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	—	0.6	—	V	

Table continues on the next page...

3.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

Table 22. NVM program/erase timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{hvp\text{gm}4}$	Longword Program high-voltage time	—	7.5	18	μs	—
$t_{h\text{versscr}}$	Sector Erase high-voltage time	—	13	113	ms	1
$t_{h\text{versall}}$	Erase All high-voltage time	—	104	904	ms	1

1. Maximum time based on expectations at cycling end-of-life.

3.4.1.2 Flash timing specifications — commands

Table 23. Flash command timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{rd1\text{sec}2k}$	Read 1s Section execution time (flash sector)	—	—	60	μs	1
t_{pgmchk}	Program Check execution time	—	—	45	μs	1
$t_{rd\text{rsrc}}$	Read Resource execution time	—	—	30	μs	1
t_{pgm4}	Program Longword execution time	—	65	145	μs	—
$t_{er\text{sscr}}$	Erase Flash Sector execution time	—	14	114	ms	2
$t_{rd1\text{all}}$	Read 1s All Blocks execution time	—	—	1.8	ms	1
$t_{rd\text{once}}$	Read Once execution time	—	—	30	μs	1
$t_{pgm\text{once}}$	Program Once execution time	—	100	—	μs	—
$t_{er\text{all}}$	Erase All Blocks execution time	—	175	1300	ms	2
$t_{vfy\text{key}}$	Verify Backdoor Access Key execution time	—	—	30	μs	1

1. Assumes 25 MHz flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.

3.4.1.3 Flash high voltage current behaviors

Table 24. Flash high voltage current behaviors

Symbol	Description	Min.	Typ.	Max.	Unit
I_{DD_PGM}	Average current adder during high voltage flash programming operation	—	2.5	6.0	mA
I_{DD_ERS}	Average current adder during high voltage flash erase operation	—	1.5	4.0	mA

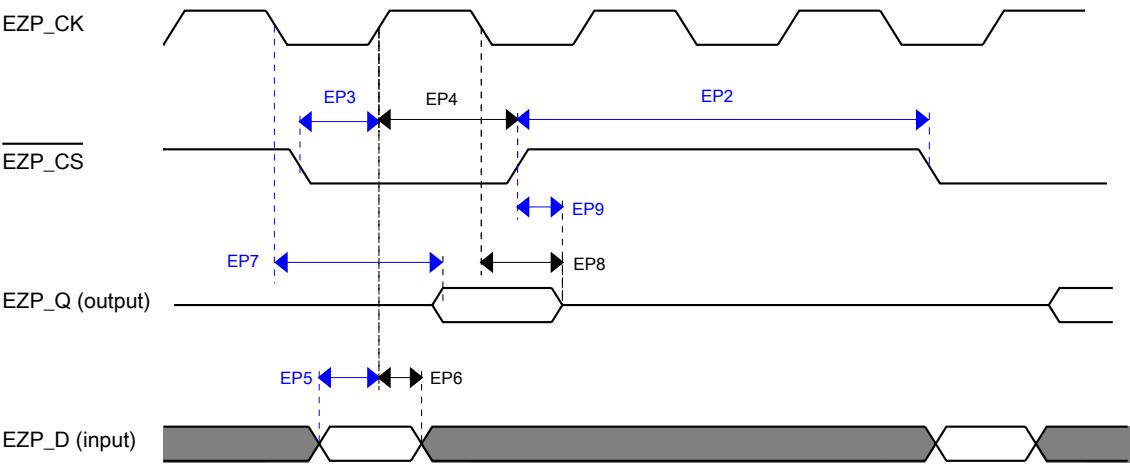


Figure 11. EzPort Timing Diagram

3.5 Security and integrity modules

There are no specifications necessary for the device's security and integrity modules.

3.6 Analog

3.6.1 ADC electrical specifications

The 16-bit accuracy specifications listed in [Table 27](#) and [Table 28](#) are achievable on the differential pins ADCx_DPx, ADCx_DMx.

All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

3.6.1.1 16-bit ADC operating conditions

Table 27. 16-bit ADC operating conditions

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
V _{DDA}	Supply voltage	Absolute	1.71	—	3.6	V	
ΔV _{DDA}	Supply voltage	Delta to V _{DD} (V _{DD} – V _{DDA})	-100	0	+100	mV	2

Table continues on the next page...

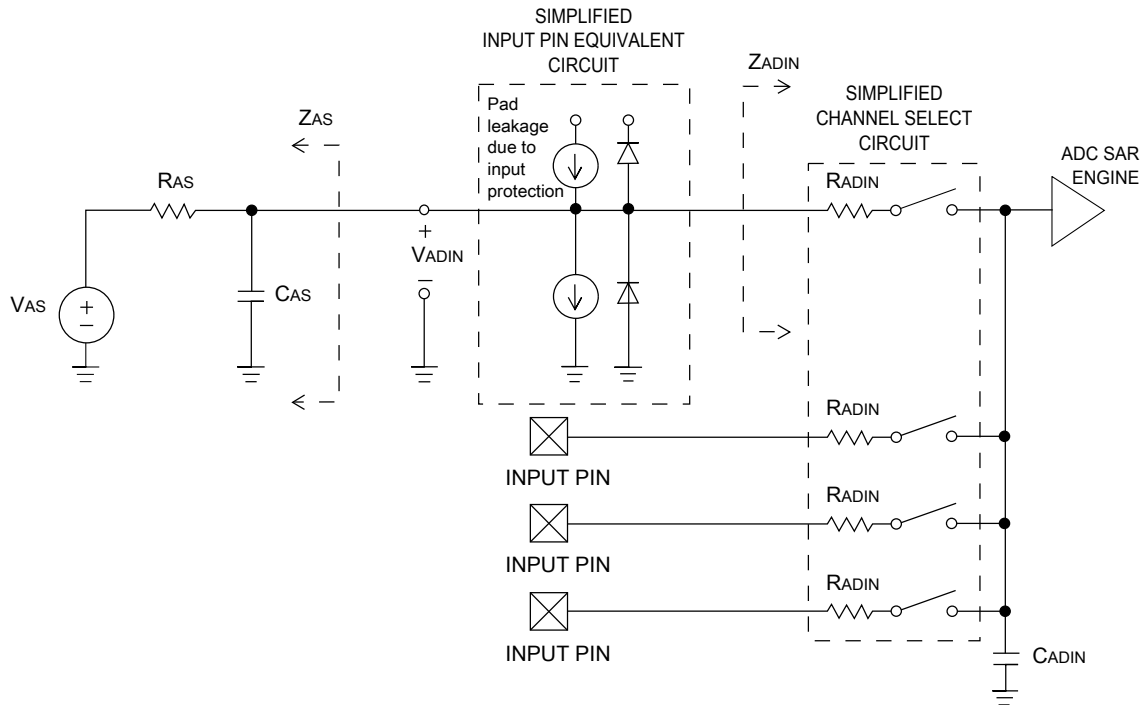


Figure 12. ADC input impedance equivalency diagram

3.6.1.2 16-bit ADC electrical characteristics

Table 28. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
I_{DDA_ADC}	Supply current		0.215	—	1.7	mA	3
f_{ADACK}	ADC asynchronous clock source	• ADLPC = 1, ADHSC = 0 • ADLPC = 1, ADHSC = 1 • ADLPC = 0, ADHSC = 0 • ADLPC = 0, ADHSC = 1	1.2 2.4 3.0 4.4	2.4 4.0 5.2 6.2	3.9 6.1 7.3 9.5	MHz MHz MHz MHz	$t_{ADACK} = 1/f_{ADACK}$
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	• 12-bit modes • <12-bit modes	— —	± 4 ± 1.4	± 6.8 ± 2.1	LSB ⁴	5
DNL	Differential non-linearity	• 12-bit modes • <12-bit modes	— —	± 0.7 ± 0.2	-1.1 to +1.9 -0.3 to 0.5	LSB ⁴	5
INL	Integral non-linearity	• 12-bit modes	—	± 1.0	-2.7 to +1.9	LSB ⁴	5

Table continues on the next page...

**Table 36. USB VREG electrical specifications
(continued)**

Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes
V _{Reg33out}	Regulator output voltage — Input supply (VREGIN) < 3.6 V, pass-through mode	2.1	—	3.6	V	2
C _{OUT}	External output capacitor	1.76	2.2	8.16	μF	
ESR	External output capacitor equivalent series resistance	1	—	100	mΩ	
I _{LIM}	Short circuit current	—	290	—	mA	

1. Typical values assume VREGIN = 5.0 V, Temp = 25 °C unless otherwise stated.

2. Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I_{Load}.

3.8.3 DSPI switching specifications (limited voltage range)

The Deserial Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the SPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

Table 37. Master mode DSPI timing (limited voltage range)

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	30	MHz	
DS1	DSPI_SCK output cycle time	2 × t _{BUS}	—	ns	
DS2	DSPI_SCK output high/low time	(t _{SCK} /2) – 2	(t _{SCK} /2) + 2	ns	
DS3	DSPI_PCS _n valid to DSPI_SCK delay	(t _{BUS} × 2) – 2	—	ns	1
DS4	DSPI_SCK to DSPI_PCS _n invalid delay	(t _{BUS} × 2) – 2	—	ns	2
DS5	DSPI_SCK to DSPI_SOUT valid	—	8.5	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-2	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	16.2	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The delay is programmable in SPIx_CTARn[PSSCK] and SPIx_CTARn[CSSCK].

2. The delay is programmable in SPIx_CTARn[PASC] and SPIx_CTARn[ASC].

Table 41. I²C timing (continued)

Characteristic	Symbol	Standard Mode		Fast Mode		Unit
		Minimum	Maximum	Minimum	Maximum	
Data hold time for I ² C bus devices	t _{HD} ; DAT	0 ²	3.45 ³	0 ⁴	0.9 ²	μs
Data set-up time	t _{SU} ; DAT	250 ⁵	—	100 ^{3, 6}	—	ns
Rise time of SDA and SCL signals	t _r	—	1000	20 + 0.1C _b ⁷	300	ns
Fall time of SDA and SCL signals	t _f	—	300	20 + 0.1C _b ⁶	300	ns
Set-up time for STOP condition	t _{SU} ; STO	4	—	0.6	—	μs
Bus free time between STOP and START condition	t _{BUF}	4.7	—	1.3	—	μs
Pulse width of spikes that must be suppressed by the input filter	t _{SP}	N/A	N/A	0	50	ns

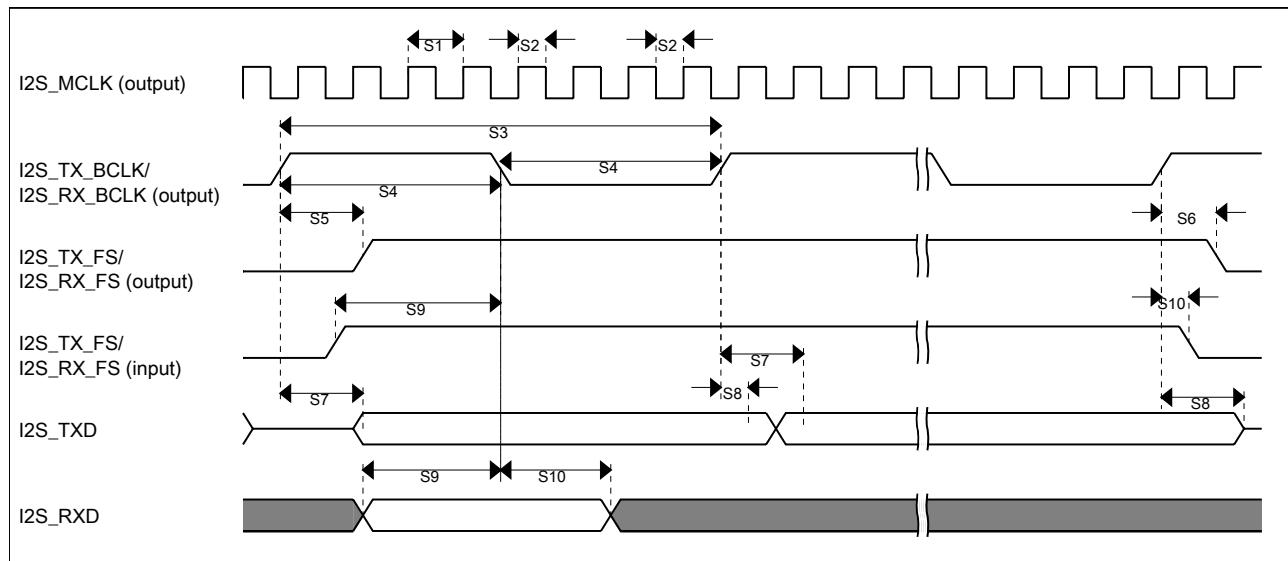
1. The maximum SCL Clock Frequency in Fast mode with maximum bus loading can only be achieved when using the High drive pins across the full voltage range and when using the Normal drive pins and VDD ≥ 2.7 V.
2. The master mode I²C deasserts ACK of an address byte simultaneously with the falling edge of SCL. If no slaves acknowledge this address byte, then a negative hold time can result, depending on the edge rates of the SDA and SCL lines.
3. The maximum t_{HD}; DAT must be met only if the device does not stretch the LOW period (t_{LOW}) of the SCL signal.
4. Input signal Slew = 10 ns and Output Load = 50 pF
5. Set-up time in slave-transmitter mode is 1 IPBus clock period, if the TX FIFO is empty.
6. A Fast mode I²C bus device can be used in a Standard mode I²C bus system, but the requirement t_{SU}; DAT ≥ 250 ns must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, then it must output the next data bit to the SDA line t_{rmax} + t_{SU}; DAT = 1000 + 250 = 1250 ns (according to the Standard mode I²C bus specification) before the SCL line is released.
7. C_b = total capacitance of the one bus line in pF.

Table 42. I²C 1 Mbps timing

Characteristic	Symbol	Minimum	Maximum	Unit
SCL Clock Frequency	f _{SCL}	0	1 ¹	MHz
Hold time (repeated) START condition. After this period, the first clock pulse is generated.	t _{HD} ; STA	0.26	—	μs
LOW period of the SCL clock	t _{LOW}	0.5	—	μs
HIGH period of the SCL clock	t _{HIGH}	0.26	—	μs
Set-up time for a repeated START condition	t _{SU} ; STA	0.26	—	μs
Data hold time for I ² C bus devices	t _{HD} ; DAT	0	—	μs
Data set-up time	t _{SU} ; DAT	50	—	ns
Rise time of SDA and SCL signals	t _r	20 + 0.1C _b ²	120	ns
Fall time of SDA and SCL signals	t _f	20 + 0.1C _b ²	120	ns
Set-up time for STOP condition	t _{SU} ; STO	0.26	—	μs
Bus free time between STOP and START condition	t _{BUF}	0.5	—	μs
Pulse width of spikes that must be suppressed by the input filter	t _{SP}	0	50	ns

Table 45. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (full voltage range) (continued)

Num.	Characteristic	Min.	Max.	Unit
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	-1.0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	27	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

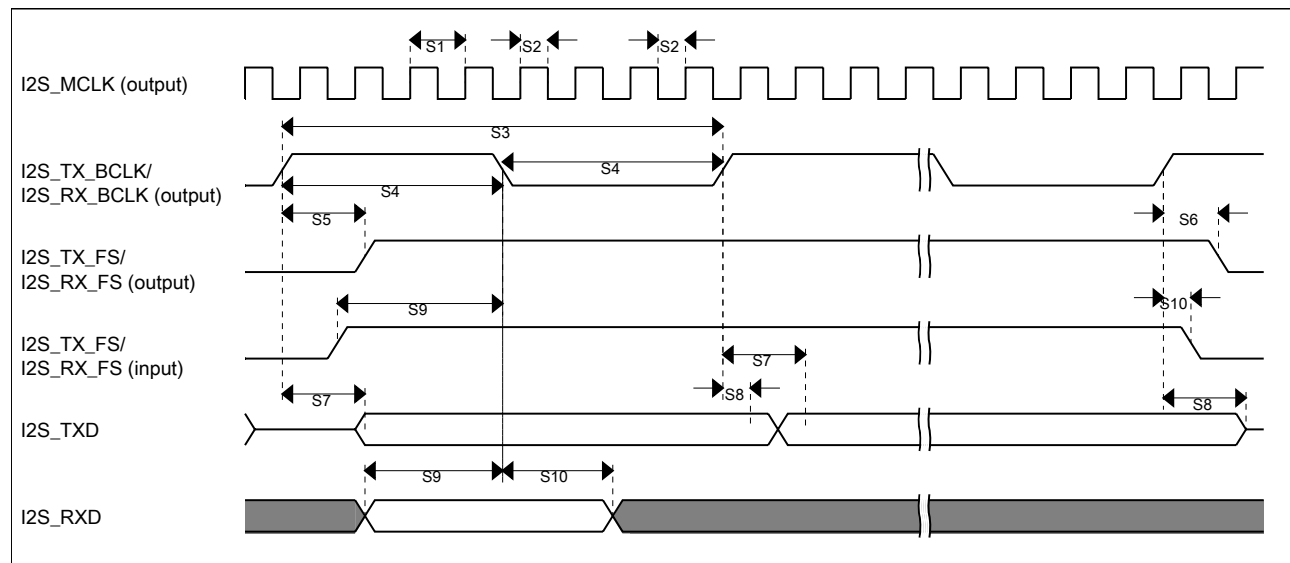
**Figure 26. I2S/SAI timing — master modes****Table 46. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	5.8	—	ns

Table continues on the next page...

Table 47. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range) (continued)

Num.	Characteristic	Min.	Max.	Unit
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	45	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	-1	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	45	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	45	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

**Figure 28. I2S/SAI timing — master modes****Table 48. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	250	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	30	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	7	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid	—	63	ns

Table continues on the next page...

Table 48. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range) (continued)

Num.	Characteristic	Min.	Max.	Unit
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	30	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	4	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid ¹	—	72	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

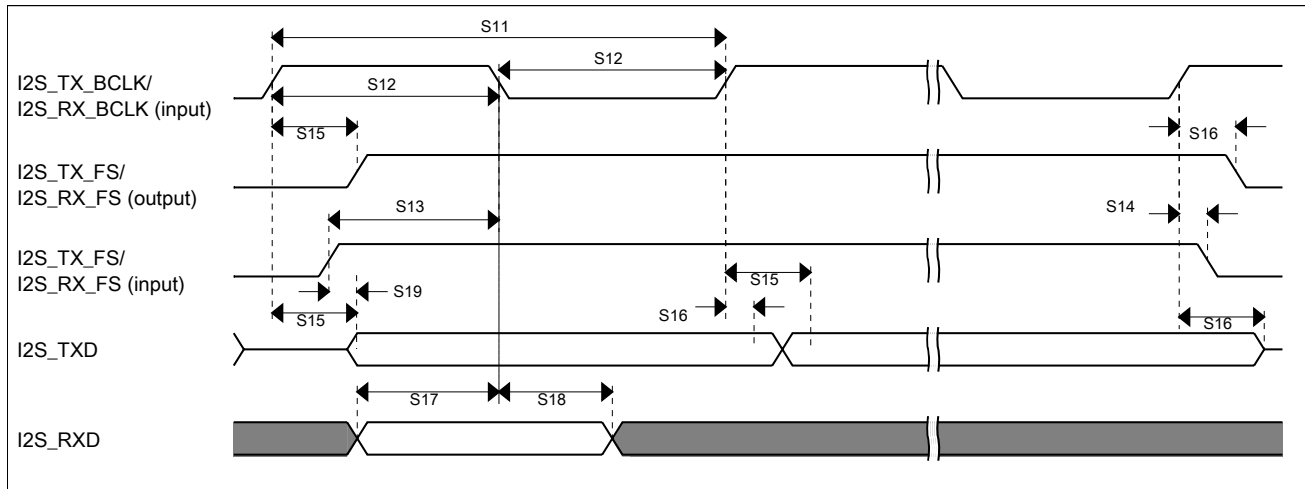


Figure 29. I2S/SAI timing — slave modes

4 Dimensions

4.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to nxp.com and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
64-pin LQFP	98ASS23234W
64-pin MAPBGA	98ASA00420D
100-pin LQFP	98ASS23308W
121-pin XFBGA	98ASA00595D

Table 49. Recommended connection for unused analog interfaces (continued)

Pin Type		Short recommendation	Detailed recommendation
GPIO/Analog	PTA18/EXTAL0	Float	Analog input - Float
GPIO/Analog	PTA19/XTAL0	Float	Analog output - Float
GPIO/Analog	PTx/ADCx	Float	Float (default is analog input)
GPIO/Analog	PTx/CMPx	Float	Float (default is analog input)
GPIO/Digital	PTA0/JTAG_TCLK	Float	Float (default is JTAG with pulldown)
GPIO/Digital	PTA1/JTAG_TDI	Float	Float (default is JTAG with pullup)
GPIO/Digital	PTA2/JTAG_TDO	Float	Float (default is JTAG with pullup)
GPIO/Digital	PTA3/JTAG_TMS	Float	Float (default is JTAG with pullup)
GPIO/Digital	PTA4/NMI_b	10k Ω pullup or disable and float	Pull high or disable in PCR & FOPT and float
GPIO/Digital	PTx	Float	Float (default is disabled)
USB	USB0_DP	Float	Float
USB	USB0_DM	Float	Float
USB	VOUT33	Tie to input and ground through 10k Ω	Tie to input and ground through 10k Ω
USB	VREGIN	Tie to output and ground through 10k Ω	Tie to output and ground through 10k Ω
VBAT	VBAT	Float	Float
VDDA	VDDA	Always connect to VDD potential	Always connect to VDD potential
VREFH	VREFH	Always connect to VDD potential	Always connect to VDD potential
VREFL	VREFL	Always connect to VSS potential	Always connect to VSS potential
VSSA	VSSA	Always connect to VSS potential	Always connect to VSS potential

5.3 K22F Pinouts

The following figure shows the pinout diagram for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.

	1	2	3	4	5	6	7	8	
A	PTE0/ CLKOUT32K	PTD7	PTD4/ LLWU_P14	PTD1	PTC11/ LLWU_P11	PTC8	PTC6/ LLWU_P10	PTC5/ LLWU_P9	A
B	PTE1/ LLWU_P0	PTD6/ LLWU_P15	PTD3	PTC10	PTC9	PTC7	PTC2	PTC4/ LLWU_P8	B
C	PTD5	PTD2/ LLWU_P13	PTD0/ LLWU_P12	VSS	VDD	PTC1/ LLWU_P6	PTB19	PTC3/ LLWU_P7	C
D	USB0_DM	VREGIN	PTA0	PTA1	PTA3	PTB18	PTB17	PTC0	D
E	USB0_DP	VOUT33	VSS	VDD	PTA2	PTB16	PTB2	PTB3	E
F	ADC0_DM0/ ADC1_DM3	ADC1_DM0/ ADC0_DM3	VSSA	VDDA	PTA5	PTB1	PTB0/ LLWU_P5	RESET_b	F
G	ADC0_DP0/ ADC1_DP3	ADC1_DP0/ ADC0_DP3	VREFL	VREFH	PTA4/ LLWU_P3	PTA13/ LLWU_P4	VDD	PTA19	G
H	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	XTAL32	EXTAL32	VBAT	PTA12	VSS	PTA18	H
	1	2	3	4	5	6	7	8	

Figure 31. K22F 64 MAPBGA Pinout Diagram (transparent top view)

Term	Definition
	NOTE: The likelihood of permanent chip failure increases rapidly as soon as a characteristic begins to exceed one of its operating ratings.
Operating requirement	A specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip
Operating behavior	A specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions
Typical value	A specified value for a technical characteristic that: - Lies within the range of values specified by the operating behavior - Is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions NOTE: Typical values are provided as design guidelines and are neither tested nor guaranteed.

7.2 Examples

Operating rating:

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	-0.3	1.2	V

Operating requirement:

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	0.9	1.1	V

Operating behavior that includes a typical value:

Symbol	Description	Min.	Typ.	Max.	Unit
I_{WP}	Digital I/O weak pullup/pulldown current	10	70	130	μA

7.3 Typical-value conditions

Typical values assume you meet the following conditions (or other conditions as specified):